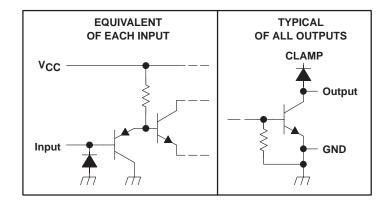
- Characterized for Use to 300 mA
- No Output Latch-Up at 55 V (After Conducting 300 mA)
- High-Voltage Outputs (100 V Typ)
- Output Clamp Diodes for Transient Suppression (300 mA, 70 V)
- TTL- or MOS-Compatible Diode-Clamped Inputs
- pnp Transistor Inputs Reduce Input Current
- Standard Supply Voltage
- Suitable for Hammer-Driver Applications
- Plastic DIP (P) With Copper-Lead Frame **Provides Cooler Operation and Improved** Reliability

description

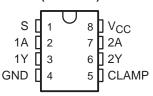
The SN75476 through SN75478 are dual peripheral drivers designed for use in systems that require high current, high voltage, and fast switching times. The SN75476, SN75477, and SN75478 provide AND, NAND, and OR drivers respectively. These devices have diode-clamped inputs as well as high-current, high-voltage clamp diodes on the outputs for inductive transient protection.

The SN75476, SN75477, and SN75478 drivers are characterized for operation from 0°C to 70°C.

schematics of inputs and outputs



D OR P PACKAGE (TOP VIEW)



Function Tables

SN75476 (each AND driver)

INPU	OUTPUT				
Α	A S				
Н	Н	Н			
L	Χ	L			
Х	L	L			

SN75477 (each NAND driver)

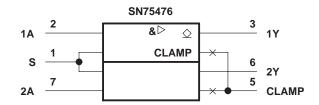
INPU	OUTPUT					
Α	A S					
Н	Н	L				
L	X	Н				
Х	L	Н				

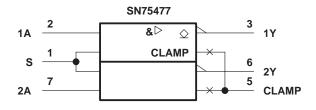
SN75478 (each OR driver)

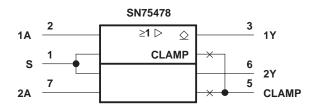
INPU	OUTPUT			
Α	A S			
Н	Х	Н		
Х	Н	Н		
L	L	L		

H = high level, L = low level X = irrelevant

logic symbols†

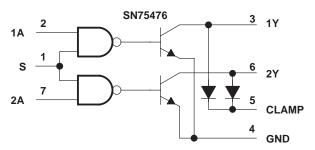




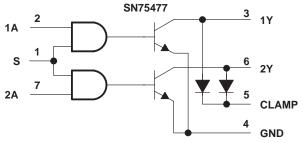


[†] These symbols are in accordance with ANSI/IEEE Std 91-1984 and IEC publication 617-12.

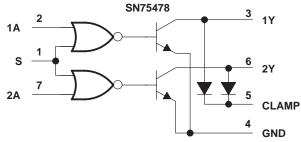
logic diagrams (positive logic)



Positive Logic: Y = AS or $\overline{A}+\overline{S}$



Positive Logic: $Y = \overline{AS}$ or $\overline{A} + \overline{S}$



Positive Logic: Y = A+S or $\overline{A} \overline{S}$

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absolute maximum ratings over operating free-air temperature range (unless otherwise noted)

Supply voltage, V _{CC} (see Note 1)	7 V
Input voltage, V _I	5.5 V
Continuous output current (see Note 2)	400 mA
Peak output current: $t_W \le 10$ ms, duty cycle $\le 50\%$	500 mA
$t_W \le 30 \text{ ns}, \text{ duty cycle} \le 0.002\% \dots$	3 A
Output clamp current, I _{OK}	400 mA
Continuous total power dissipation	See Dissipation Rating Table
Operating free-air temperature range, T _A	0°C to 70°C
Storage temperature range, T _{stq}	
Lead temperature 1,6 mm (1/16 inch) from case for 10 seconds	260°C

NOTES: 1. Voltage values are with respect to network GND.

2. Both halves of this dual circuit may conduct rated current simultaneously; however, power dissipation averaged over a short time interval must fall within the continuous power dissipation ratings.

DISSIPATION RATING TABLE

PACKAGE	$T_{\mbox{A}} \le 25^{\circ}\mbox{C}$ POWER RATING	DERATING FACTOR ABOVE T _A = 25°C	T _A = 70°C POWER RATING		
D	725 mW	5.8 mW/°C	464 mW		
Р	1000 mW	8.0 mW/°C	640 mW		

recommended operating conditions

	MIN	NOM	MAX	UNIT
Supply voltage, V _{CC}	4.5	5	5.5	V
High-level input voltage, VIH	2			V
Low-level input voltage, V _{IL}			0.8	V
Operating free-air temperature, TA	0		70	°C

SN75476 THRU SN75478 DUAL PERIPHERAL DRIVERS

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electrical characteristics over recommended operating free-air temperature range

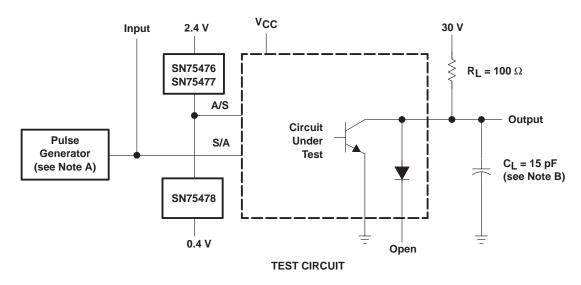
	PARAMETER		TEST C	TEST CONDITIONS			MAX	UNIT
VIK	Input clamp voltage		I _I = -12 mA	I _I = -12 mA			-1.5	V
			V _{CC} = 4.5 V,	I _{OL} = 100 mA		0.16	0.3	
VOL	Low-level output voltage		$V_{IH} = 2 V$	I _{OL} = 175 mA		0.22	0.5	V
			V _{IL} = 0.8 V	$I_{OL} = 300 \text{ mA}$		0.33	0.6	
V _{O(BR)}	Output breakdown voltage		$V_{CC} = 4.5 \text{ V},$	I _{OH} = 100 μA	70	100		V
V _{R(K)}	Output clamp reverse voltage		$V_{CC} = 4.5 \text{ V},$	I _R = 100 μA	70	100		V
V _{F(K)}	Output clamp forward voltage		V _{CC} = 4.5 V,	IF = 300 mA	0.8	1.15	1.6	V
ЮН	High-level output current		V _{CC} = 4.5 V, V _{IL} = 0.8 V,	V _{IH} = 2 V, V _{OH} = 70 V		1	100	μΑ
lН	High-level input current	High-level input current		V _I = 5.5 V		0.01	10	μΑ
	Laurent aumant	A input	V 55V	V 00V		-80	-110	^
¹IL	Low-level input current	S input	V _{CC} = 5.5 V,	$V_I = 0.8 V$		-160	-220	μΑ
		SN75476		V _I = 5 V		10	17	
ІССН	Supply current, outputs high	SN75477	V _{CC} = 5.5 V	V _I = 0		10	17	mA
		SN75478		V _I = 5 V		10	17	
		SN75476		V _I = 0		54	75	
ICCL	Supply current, outputs low	SN75477	V _{CC} = 5.5 V	V _I = 5 V		54	75	mA
		SN75478		V _I = 0		54	75	

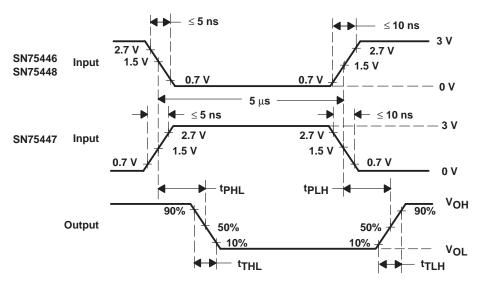
[†] All typical values are at $V_{CC} = 5 \text{ V}$, $T_A = 25^{\circ}\text{C}$.

switching characteristics, V_{CC} = 5 V, T_A = 25 $^{\circ}C$

	PARAMETER	TEST CO	NDITIONS	MIN	TYP	200 350 I			
^t PLH	Propagation delay time, low-to-high-level output				200	350	ns		
t _{PHL}	Propagation delay time, high-to-low-level output	$C_L = 15 pF,$	$R_L = 100 \Omega$,		200	350	ns		
tTLH	Transition time, low-to-high-level output	See Figure 1		50	125	ns			
tTHL	Transition time, high-to-low-level output				90	125	ns		
VOH	High-level output voltage after switching	V _S = 55 V, See Figure 2	$I_O \approx 300 \text{ mA},$	V _S -18			mV		

PARAMETER MEASUREMENT INFORMATION





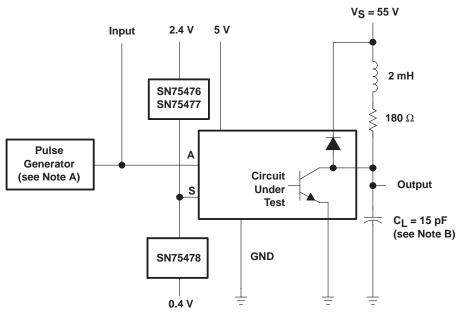
NOTES: A. The pulse generator has the following characteristics: PRR = 100 kHz, $Z_O = 50 \Omega$.

B. C_L includes probe and jig capacitance.

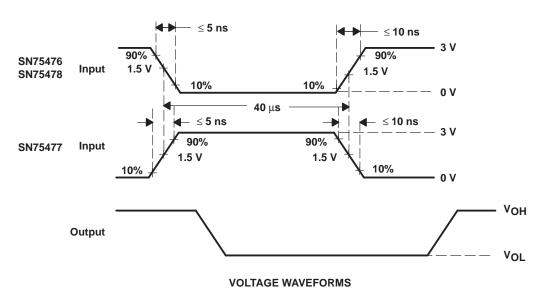
Figure 1. Test Circuit and Voltage Waveforms, Switching Characteristics

VOLTAGE WAVEFORMS

PARAMETER MEASUREMENT INFORMATION







NOTES: A. The pulse generator has the following characteristics: PRR = 12.5 kHz, $Z_O = 50 \Omega$.

B. C_L includes probe and jig capacitance.

Figure 2. Latch-Up Test Circuit and Voltage Waveforms

PACKAGE OPTION ADDENDUM



com 18-Sep-2008

PACKAGING INFORMATION

Orderable Device	Status ⁽¹⁾	Package Type	Package Drawing	Pins	Package Qty	Eco Plan ⁽²⁾	Lead/Ball Finish	MSL Peak Temp (3)
SN75476D	OBSOLETE	SOIC	D	8		TBD	Call TI	Call TI
SN75476DR	OBSOLETE	SOIC	D	8		TBD	Call TI	Call TI
SN75476P	OBSOLETE	PDIP	Р	8		TBD	Call TI	Call TI
SN75477D	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN75477DE4	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN75477DG4	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN75477DR	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN75477DRE4	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN75477DRG4	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN75477P	ACTIVE	PDIP	Р	8	50	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type
SN75477PE4	ACTIVE	PDIP	Р	8	50	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type
SN75478D	OBSOLETE	SOIC	D	8		TBD	Call TI	Call TI
SN75478P	ACTIVE	PDIP	Р	8	50	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type
SN75478PE4	ACTIVE	PDIP	Р	8	50	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type

⁽¹⁾ The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.

TBD: The Pb-Free/Green conversion plan has not been defined.

Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

Pb-Free (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

(3) MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

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PACKAGE OPTION ADDENDUM

18-Sep-2008

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TAPE AND REEL INFORMATION





A0	Dimension designed to accommodate the component width
В0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal

	Device		Package Drawing			Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
I	SN75477DR	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1



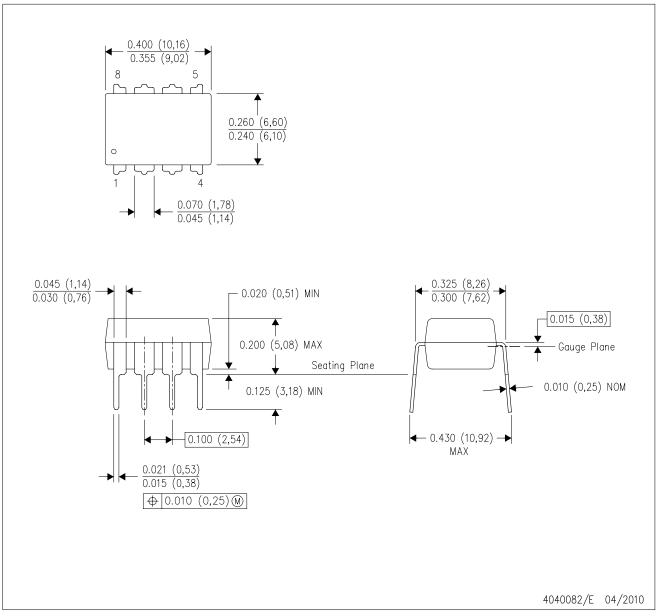


*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
SN75477DR	SOIC	D	8	2500	340.5	338.1	20.6

P (R-PDIP-T8)

PLASTIC DUAL-IN-LINE PACKAGE



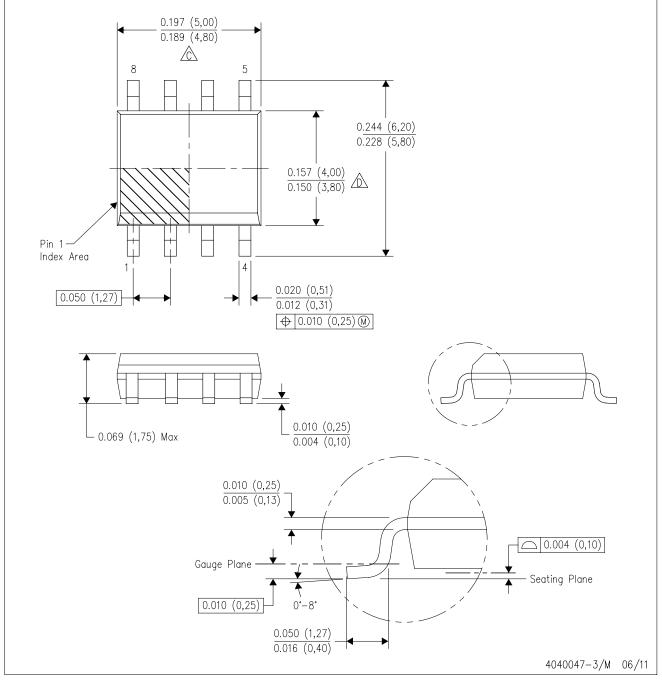
NOTES:

- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- C. Falls within JEDEC MS-001 variation BA.



D (R-PDSO-G8)

PLASTIC SMALL OUTLINE



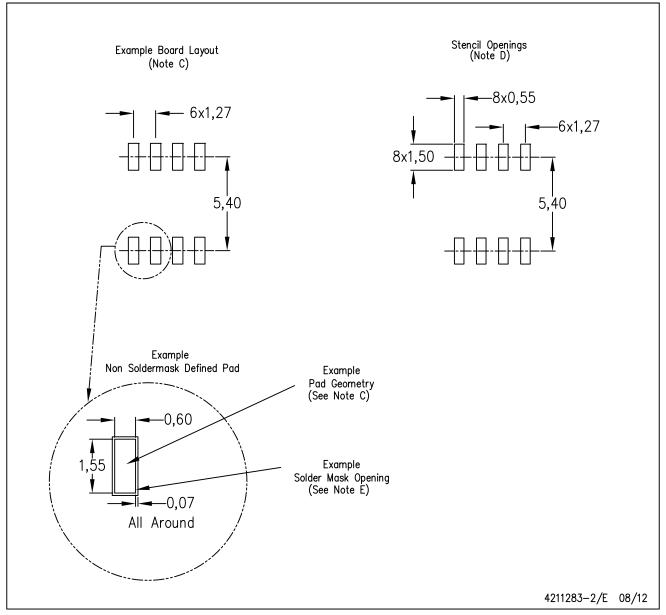
NOTES:

- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.006 (0,15) each side.
- Body width does not include interlead flash. Interlead flash shall not exceed 0.017 (0,43) each side.
- E. Reference JEDEC MS-012 variation AA.



D (R-PDSO-G8)

PLASTIC SMALL OUTLINE



NOTES:

- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Publication IPC-7351 is recommended for alternate designs.
- D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC-7525 for other stencil recommendations.
- E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.



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